SN74CB3T16212 24-BIT FET BUS-EXCHANGE SWITCH, 2.5-V/3.3-V LOW-VOLTAGE BUS SWITCH

RUMENTS www.ti.com

WITH 5-V-TOLERANT LEVEL SHIFTER SCDS157A-OCTOBER 2003-REVISED FEBRUARY 2005

FE	EATURES	DGG OR DGV	PACKAGE
•	Member of the Texas Instruments Widebus™ Family	(TOP V	
•	Output Voltage Translation Tracks V _{CC}	S0[1	56 S1
•	Supports Mixed-Mode Signal Operation on All	1A1 🛛 2	55 S2
	Data I/O Ports	1A2 🛛 3	54 [1B1
	– 5-V Input Down to 3.3-V Output Level Shift	2A1 🛛 4	53 3 1B2
	With 3.3-V V _{CC}	2A2 5	52 2B1
	– 5-V/3.3-V Input Down to 2.5-V Output Level	3A1 🛛 6	51 2B2
	Shift With 2.5-V V _{CC}	3A2 [7	50 3B1
•	5-V-Tolerant I/Os With Device Powered Up or		49 GND
	Powered Down	4A1 🛛 9 4A2 🗍 10	48 3B2 47 4B1
•	Bidirectional Data Flow, With Near-Zero	4A2 [10 5A1 [11	47 L 4B1 46 4B2
•	Propagation Delay	5A2 12	46 U 462 45 U 5B1
•	Low ON-State Resistance (r _{on}) Characteristics	6A1 13	43 5B1 44 5B2
•	$(r_{on} = 5 \Omega \text{ Typ})$	6A2 14	43 6B1
•	Low Input/Output Capacitance Minimizes	7A1 15	42 6B2
•	Loading (C _{io(OFF)} = 9 pF Typ)	7A2 16	41 7B1
	Data and Control Inputs Provide Undershoot	V _{CC} [] 17	40 0 7B2
•	Clamp Diodes	8A1 🛛 18	39 🛛 8B1
	•	GND 🛛 19	38 🛛 GND
•	Low Power Consumption ($I_{CC} = 70 \ \mu A \ Max$)	8A2 🛛 20	37 🛛 8B2
•	V _{CC} Operating Range From 2.3 V to 3.6 V	9A1 🛛 21	36] 9B1
٠	Data I/Os Support 0-V to 5-V Signaling Levels	9A2 🛛 22	35 🛛 9B2
	(0.8 V, 1.2 V, 1.5 V, 1.8 V, 2.5 V, 3.3 V, 5 V)	10A1 🛛 23	34 [10B1
٠	Control Inputs Can Be Driven by TTL or	10A2 🛛 24	33 [10B2
	5-V/3.3-V CMOS Outputs	11A1 🛛 25	32 11B1
٠	I _{off} Supports Partial-Power-Down Mode	11A2 26	31 🛛 11B2
	Operation	12A1 27	30 12B1

- Latch-Up Performance Exceeds 250 mA Per JESD 17
- ESD Performance Tested Per JESD 22
 - 2000-V Human-Body Model(A114-B, Class II) - 1000-V Charged-Device Model (C101)
- Supports Digital Applications: Level • Translation, PCI Interface, USB Interface, Memory Interleaving, and Bus Isolation
- Ideal for Low-Power Portable Equipment

DESCRIPTION/ORDERING INFORMATION

The SN74CB3T16212 is a high-speed TTL-compatible FET bus-exchange switch, with low ON-state resistance (ron), allowing for minimal propagation delay. The device fully supports mixed-mode signal operation on all data I/O ports by providing voltage translation that tracks V_{CC}. The SN74CB3T16212 supports systems using 5-V TTL, 3.3-V LVTTL, and 2.5-V CMOS switching standards, as well as user-defined switching levels (see Figure 1).

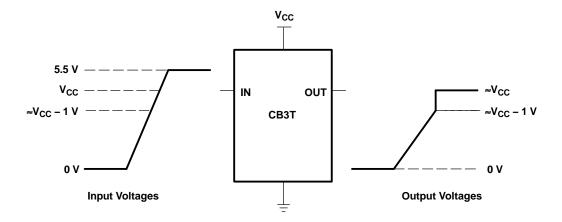


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29 12B2

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NOTE: If the input high-voltage (V_{IH}) level is greater than or equal to $V_{CC} - 1$ V and less than or equal to 5.5 V, the output high-voltage (V_{OH}) level is equal to approximately the V_{CC} voltage level.

Figure 1. Typical DC Voltage Translation Characteristics

The SN74CB3T16212 operates as a 24-bit bus switch or as a 12-bit bus exchange that provides data exchanging between four signal ports. The select (S0, S1, S2) inputs control the data path of the bus-exchange switch. When the bus-exchange switch is ON, the A port is connected to the B port, allowing bidirectional data flow between ports. When the bus-exchange switch is OFF, a high-impedance state exists between the A and B ports.

This device is fully specified for partial-power-down applications using I_{off}. The I_{off} feature ensures that damaging current will not backflow through the device when it is powered down. The device has isolation during power off.

To ensure the high-impedance state during power up or power down, each select input should be tied to GND through a pulldown resistor; the minimum value of the resistor is determined by the current-sourcing capability of the driver.

T _A	PACKAG	E ⁽¹⁾	ORDERABLE PART NUMBER	TOP-SIDE MARKING			
	TSSOP – DGG	Tape and reel	SN74CB3T16212DGGR	CB3T16212			
40°C to 95°C	TVSOP – DGV	Tape and reel	SN74CB3T16212DGVR	KR212			
–40°C to 85°C	VFBGA – GQL Tape and reel		SN74CB3T16212GQLR	- KR212			
	VFBGA – ZQL (Pb-free)	Tape and reel	SN74CB3T16212ZQLR	- KR212			

ORDERING INFORMATION

(1) Package drawings, standard packing quantities, thermal data, symbolization, and PCB design guidelines are available at www.ti.com/sc/package.

TEXAS INSTRUMENTS www.ti.com

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	GQL OR ZQL PACKAGE (TOP VIEW)										
		1	2	3	4	5	6				
Α	$\left(\right)$	С	С	С	С	С	С				
в		С	\bigcirc	\bigcirc	С	С	С				
С		С	\bigcirc	\bigcirc	\bigcirc	\bigcirc	С				
D		С	\bigcirc	\bigcirc	\bigcirc	\bigcirc	С				
Е		С	\bigcirc			\bigcirc	С				
F		С	\bigcirc			\bigcirc	\bigcirc				
G		С	\bigcirc	\bigcirc	\bigcirc	С	С				
н		С	\bigcirc	С	С	С	С				
J		О	С	С	\bigcirc	С	С				
κ		С	С	С	С	С	С				
	~							/			

TERMINAL ASSIGNMENTS

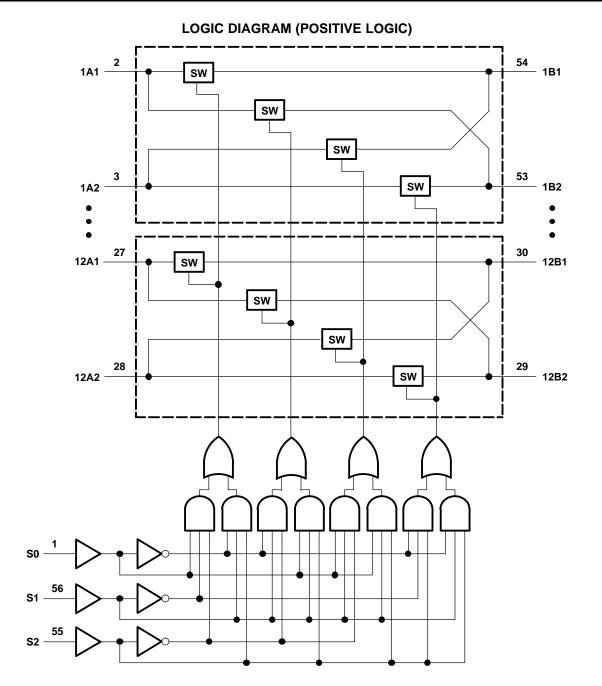
	1	2	3	4	5	6
Α	1A2	1A1	S0	S1	S2	1B1
В	3A1	2A2	2A1	1B2	2B1	2B2
С	4A1	GND	3A2	3B1	GND	3B2
D	5A2	4A2	5A1	4B2	4B1	5B1
Е	6A2	6A1			5B2	6B1
F	7A1	7A2			7B1	6B2
G	V _{CC}	GND	8A1	8B1	GND	7B2
Н	8A2	9A1	9A2	9B2	9B1	8B2
J	10A1	10A2	11A1	11B1	10B2	10B1
К	11A2	12A1	12A2	12B2	12B1	11B2

	INPUTS	;	INPUTS/C	OUTPUTS	FUNCTION
S2	S 1	S0	A1	A2	FUNCTION
L	L	L	Z	Z	Disconnect
L	L	Н	B1 port	Z	A1 port = B1 port
L	Н	L	B2 port	Z	A1 port = B2 port
L	Н	н	Z	B1 port	A2 port = B1 port
Н	L	L	Z	B2 port	A2 port = B2 port
Н	L	Н	Z	Z	Disconnect
н	Н	L	B1 port	B2 port	A1 port = B1 port A2 port = B2 port
н	Н	Н	B2 port	B1 port	A1 port = B2 port A2 port = B1 port

FUNCTION TABLE

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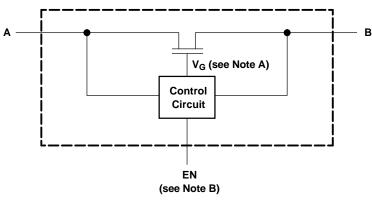






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SIMPLIFIED SCHEMATIC, EACH FET SWITCH (SW)



- A. Gate voltage (V_G) is equal to approximately V_{CC} + V_T when the switch is ON and $V_I > V_{CC} + V_T$.
- B. EN is the internal enable signal applied to the switch.

ABSOLUTE MAXIMUM RATINGS⁽¹⁾

over free-air temperature range (unless otherwise noted)

			MIN	MAX	UNIT	
V _{CC}	Supply voltage range ⁽²⁾		-0.5	7	V	
V _{IN}	Control input voltage range ⁽²⁾⁽³⁾		-0.5	7	V	
V _{I/O}	Switch I/O voltage range ⁽²⁾⁽³⁾⁽⁴⁾					
I _{IK}	Control input clamp current	V _{IN} < 0		-50	mA	
I _{I/OK}	I/O port clamp current	V _{I/O} < 0		-50	mA	
I _{I/O}	ON-state switch current ⁽⁵⁾			±128	mA	
	Continuous current through V_{CC} or GND			±100	mA	
		DGG package		64		
θ_{JA}	Package thermal impedance ⁽⁶⁾	DGV package		48	°C/W	
		GQL/ZQL package		42		
T _{stg}	Storage temperature range		-65	150	°C	

(1) Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

(2) All voltages are with respect to ground, unless otherwise specified.

(3) The input and output volrage ratings may be exceeded if the input and output clamp-current ratings are observed.

(4) V_I and V_O are used to denote specific conditions for $V_{I/O}$.

(5) I_{I} and I_{O} are used to denote specific conditions for $I_{I/O}$.

(6) The package thermal impedance is calculated in accordance with JESD 51-7.

RECOMMENDED OPERATING CONDITIONS⁽¹⁾

			MIN	MAX	UNIT	
V _{CC}	Supply voltage		2.3	3.6	V	
VIH		V_{CC} = 2.3 V to 2.7 V	1.7	5.5	V	
VIH	High-level control input voltage	$V_{CC} = 2.7 \text{ V} \text{ to } 3.6 \text{ V}$	2	5.5	V	
V		$V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$		0.7		
VIL	Low-level control input voltage	V_{CC} = 2.7 V to 3.6 V	0	0.8	v	
V _{I/O}	Data input/output voltage		0	5.5	V	
T _A	Operating free-air temperature	perating free-air temperature				

 All unused control inputs of the device must be held at V_{CC} or GND to ensure proper device operation. Refer to the TI application report, Implications of Slow or Floating CMOS Inputs, literature number SCBA004.



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ELECTRICAL CHARACTERISTICS⁽¹⁾

PAR	AMETER	TEST CONDITION	S	MIN	TYP ⁽²⁾	MAX	UNIT				
V _{IK}		$V_{CC} = 3 V, I_{I} = -18 mA$				-1.2	V				
V _{OH}		See Figures 3 and 4									
I _{IN}	Control inputs	V_{CC} = 3.6 V, V_{IN} = 3.6 V to 5.5 V or GND				±10	μA				
			$V_{I} = V_{CC} - 0.7 \text{ V to 5.5 V}$			±20					
I _I		V_{CC} = 3.6 V, V_{IN} = V_{CC} or GND, Switch ON	$V_{I} = 0.7$ V to $V_{CC} - 0.7$ V				μA				
I _{OZ} ⁽³⁾			V _I = 0 to 0.7 V			±5	±5				
		V_{CC} = 3.6 V, V_{I} = 0, V_{IN} = V_{CC} or GND, V_{O} = 0	to 5.5 V, Switch OFF			±10	μΑ				
l _{off}		$V_{CC} = 0, V_{I} = 0, V_{O} = 0 \text{ to } 5.5 \text{ V}$				10	μΑ				
		$V_{CC} = 3.6 \text{ V}, V_{IN} = V_{CC} \text{ or GND}, I_{I/O} = 0,$	$V_{I} = V_{CC}$ or GND			70	A				
I _{CC}		Switch ON or OFF	V _I = 5.5 V			70	μA				
$\Delta I_{CC}^{(4)}$	Control inputs	V_{CC} = 3 V to 3.6 V, One input at V_{CC} – 0.6 V, C	Other inputs at V _{CC} or GND			300	μΑ				
C _{in}	Control inputs	V_{CC} = 3.3 V, V_{IN} = V_{CC} or GND			4		pF				
Cio(OFF)	V_{CC} = 3.3 V, V_{IN} = V_{CC} or GND, $V_{I/O}$ = 5.5 V, 3	.3 V, or GND, Switch OFF		9		pF				
		$V_{CC} = 3.3 \text{ V}, V_{IN} = V_{CC} \text{ or GND}, \text{ Switch ON}$	V _{I/O} = 5.5 V or 3.3 V		8		~ Г				
C _{io(ON)}		$v_{\rm CC} = 3.3 \text{ v}, v_{\rm IN} = v_{\rm CC} \text{ or GND}, \text{ Switch ON}$	$V_{I/O} = GND$		23		pF				
		$V_{1} = 2.2 V_{1} TYP at V_{2} = 2.5 V_{1} V_{2} = 0$	I _O = 24 mA		5	9.5					
r (5)		V_{CC} = 2.3 V, TYP at V_{CC} = 2.5 V, V_{I} = 0	I _O = 16 mA		5	9.5	Ω				
r _{ON} ⁽⁵⁾		$V_{CC} = 3 V. V_1 = 0$	I _O = 64 mA		5	8.5	12				
		$v_{CC} = 3 v, v_1 = 0$	I _O = 32 mA		5	8.5					

(1)

 V_{IN} and I_{IN} refer to control inputs. V_I, V_O, I_I, and I_O refer to data pins. All typical values are at V_{CC} = 3.3 V (unless otherwise noted), T_A = 25°C. (2)

(3) For I/O ports, the parameter I_{OZ} includes the input leakage current.

(4) This is the increase in supply current for each input that is at the specified TTL voltage level, rather than V_{CC} or GND.

(5) Measured by the voltage drop between A and B terminals at the indicated current throught the switch. ON-state resistance is determined by the lower of the voltages of the two (A or B) terminals.

SWITCHING CHARACTERISTICS

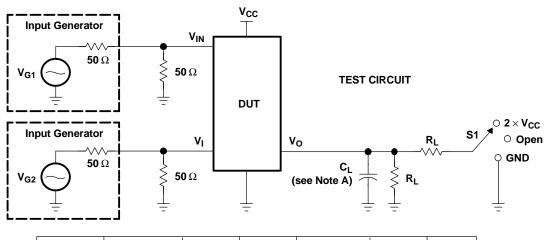
over operating free-air temperature range (unless otherwise noted) (see Figure 2)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	V _{CC} = ± 0.2	2.5 V 2 V	V _{CC} = 1 ± 0.3	3.3 V 3 V	UNIT
	(INFOT)	(001701)	MIN	MAX	MIN	MAX	(
t _{pd} (1)	A or B	B or A		0.15		0.25	ns
t _{pd(s)}	S	А	1	15.5	1	11.5	ns
t _{en}	S	В	1	15	1	12	ns
t _{dis}	S	В	1	12	1	10.5	ns

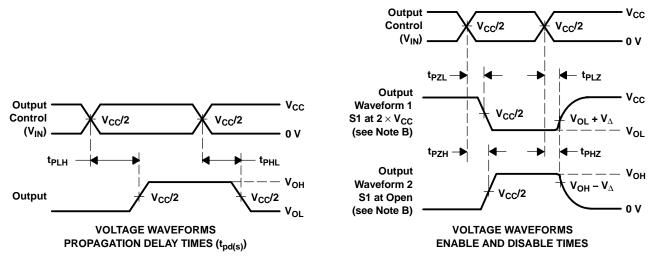
(1) The propagation delay is the calculated RC time constant of the typical ON-state resistance of the switch and the specified load capaitance, when driven by an ideal voltage source (zero output impedance).

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PARAMETER MEASUREMENT INFORMATION



TEST	V _{CC}	S1	RL	VI	CL	V_{Δ}
t _{pd(s)}	$\begin{array}{c} \textbf{2.5 V} \pm \textbf{0.2 V} \\ \textbf{3.3 V} \pm \textbf{0.3 V} \end{array}$	Open Open	500 Ω 500 Ω	3.6 V or GND 5.5 V or GND	30 pF 50 pF	
t _{PLZ} /t _{PZL}	$\begin{array}{c} \textbf{2.5 V} \pm \textbf{0.2 V} \\ \textbf{3.3 V} \pm \textbf{0.3 V} \end{array}$	$\begin{array}{c} \textbf{2} \times \textbf{V}_{\textbf{CC}} \\ \textbf{2} \times \textbf{V}_{\textbf{CC}} \end{array}$	500 Ω 500 Ω	GND GND	30 pF 50 pF	0.15 V 0.3 V
t _{PHZ} /t _{PZH}	$\begin{array}{c} \textbf{2.5 V} \pm \textbf{0.2 V} \\ \textbf{3.3 V} \pm \textbf{0.3 V} \end{array}$	Open Open	500 Ω 500 Ω	3.6 V 5.5 V	30 pF 50 pF	0.15 V 0.3 V



- NOTES: A. C_L includes probe and jig capacitance.
 - B. Waveform 1 is for an output with internal conditions such that the output is low, except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high, except when disabled by the output control.
 - C. All input pulses are supplied by generators having the following characteristics: PRR \leq 10 MHz, Z₀ = 50 Ω , t_r \leq 2.5 ns, t_f \leq 2.5 ns.
 - D. The outputs are measured one at a time, with one transition per measurement.
 - E. t_{PLZ} and t_{PHZ} are the same as t_{dis} .
 - F. t_{PZL} and t_{PZH} are the same as t_{en} .
 - G. t_{PLH} and t_{PHL} are the same as $t_{pd(s)}$. The tpd propagation delay is the calculated RC time constant of the typical ON-state resistance of the switch and the specified load capacitance, when driven by an ideal voltage source (zero output impedance).
 - H. All parameters and waveforms are not applicable to all devices.

Figure 2. Test Circuit and Voltage Waveforms



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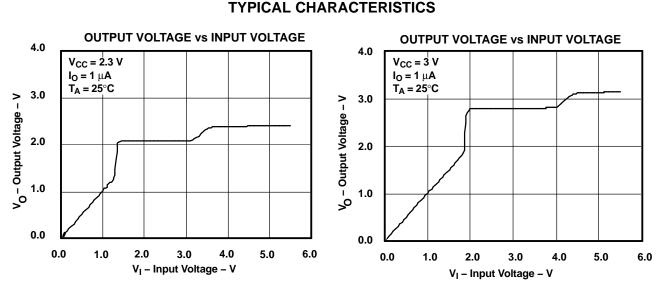


Figure 3. Data Output Voltage vs Data Input Voltage

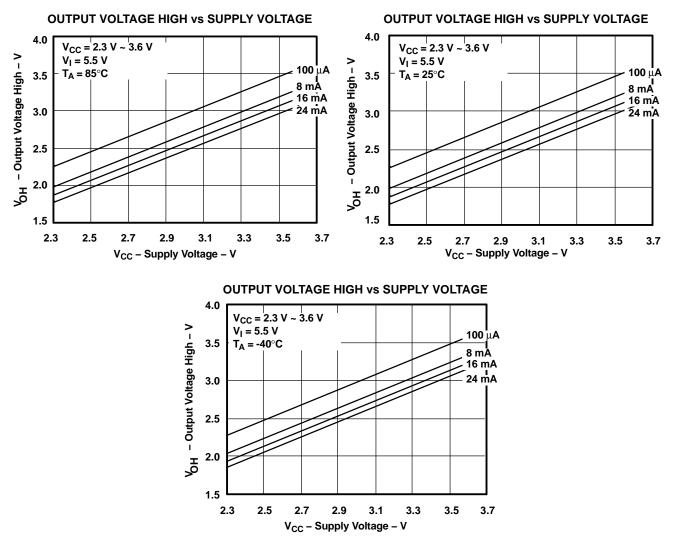


Figure 4. V_{OH} Values



PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead finish/ Ball material	MSL Peak Temp (3)	Op Temp (°C)	Device Marking (4/5)	Samples
							(6)				
SN74CB3T16212DGGR	ACTIVE	TSSOP	DGG	56	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	CB3T16212	Samples
SN74CB3T16212ZQLR	OBSOLETE	BGA MICROSTAR JUNIOR	ZQL	56		TBD	Call TI	Call TI		KR212	

⁽¹⁾ The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

⁽²⁾ RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (CI) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

⁽³⁾ MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

⁽⁴⁾ There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

⁽⁶⁾ Lead finish/Ball material - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

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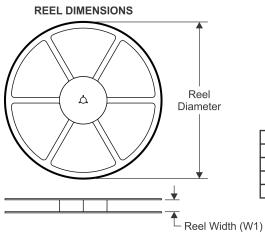
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PACKAGE MATERIALS INFORMATION

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TAPE AND REEL INFORMATION





QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal												
Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN74CB3T16212DGGR	TSSOP	DGG	56	2000	330.0	24.4	8.6	15.6	1.8	12.0	24.0	Q1

TEXAS INSTRUMENTS

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PACKAGE MATERIALS INFORMATION

7-Nov-2019



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
SN74CB3T16212DGGR	TSSOP	DGG	56	2000	367.0	367.0	45.0

PACKAGE OUTLINE

DGG0056A

TSSOP - 1.2 mm max height

SMALL OUTLINE PACKAGE



NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M. 2. This drawing is subject to change without notice. 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not

- exceed 0.15 mm per side. 4. Reference JEDEC registration MO-153.



DGG0056A

EXAMPLE BOARD LAYOUT

TSSOP - 1.2 mm max height

SMALL OUTLINE PACKAGE



NOTES: (continued)

5. Publication IPC-7351 may have alternate designs.

6. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



DGG0056A

EXAMPLE STENCIL DESIGN

TSSOP - 1.2 mm max height

SMALL OUTLINE PACKAGE



NOTES: (continued)

- 7. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 8. Board assembly site may have different recommendations for stencil design.



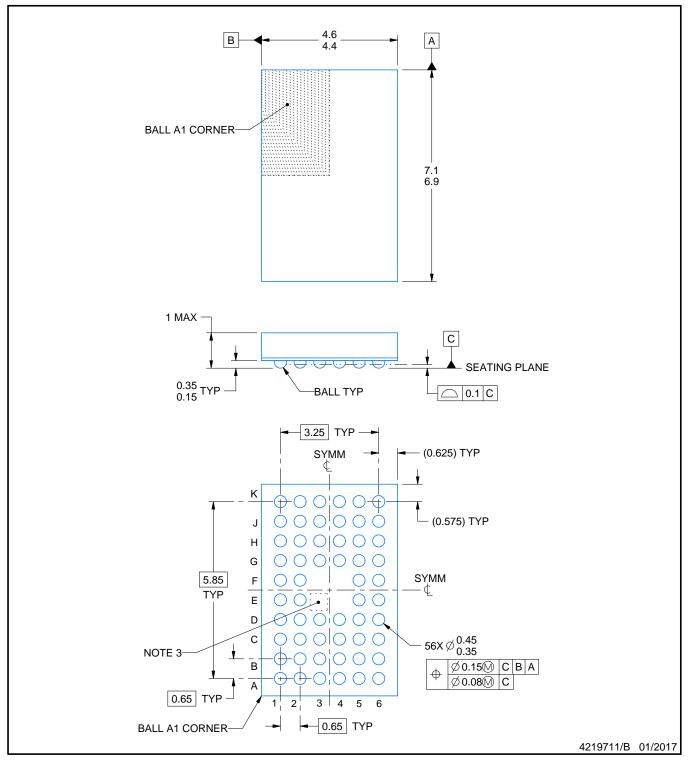
ZQL0056A



PACKAGE OUTLINE

JRBGA - 1 mm max height

PLASTIC BALL GRID ARRAY



NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M. 2. This drawing is subject to change without notice.
- 3. No metal in this area, indicates orientation.

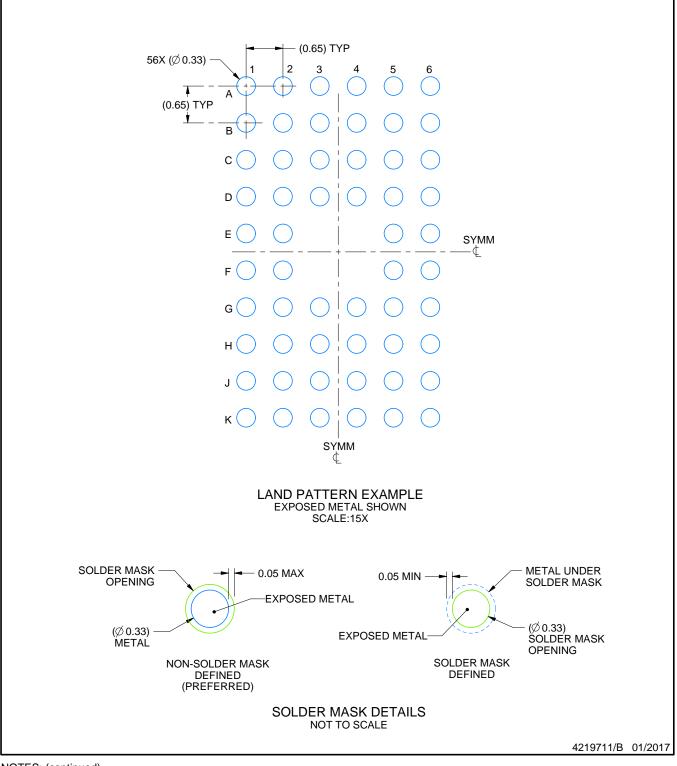


ZQL0056A

EXAMPLE BOARD LAYOUT

JRBGA - 1 mm max height

PLASTIC BALL GRID ARRAY



NOTES: (continued)

4. Final dimensions may vary due to manufacturing tolerance considerations and also routing constraints. For information, see Texas Instruments literature number SPRAA99 (www.ti.com/lit/spraa99).

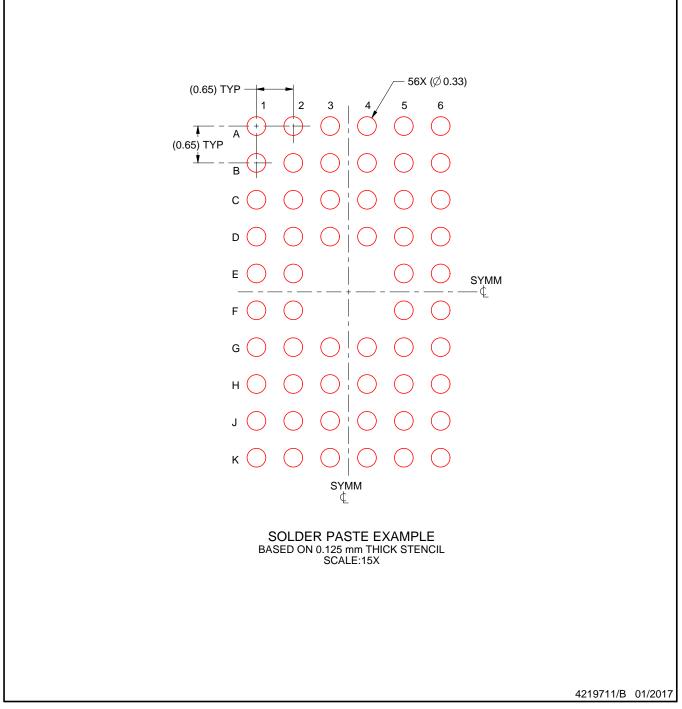


ZQL0056A

EXAMPLE STENCIL DESIGN

JRBGA - 1 mm max height

PLASTIC BALL GRID ARRAY



NOTES: (continued)

5. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release.



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